STTA1512P/PI

TURBOSWITCH ULTRA-FAST HIGH VOLTAGE DIODE

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	**15A**
V_{RRM}	**1200V**
t_{rr} **(typ)**	**55ns**
V_F **(max)**	**1.9V**

FEATURES AND BENEFITS

- ULTRA-FAST, SOFT RECOVERY.
- VERY LOW OVERALL POWER LOSSES IN BOTH THE DIODE AND THE COMPANION TRANSISTOR.
- HIGH FREQUENCY AND/OR HIGH PULSED CURRENT OPERATION.
- HIGH REVERSE VOLTAGE CAPABILITY
- INSULATED PACKAGE : DOP3I
  Electrical insulation : $2500V_{RMS}$
  Capacitance : 12pF

SOD93

STTA1512P

Isolated
DOP3I

STTA1512PI
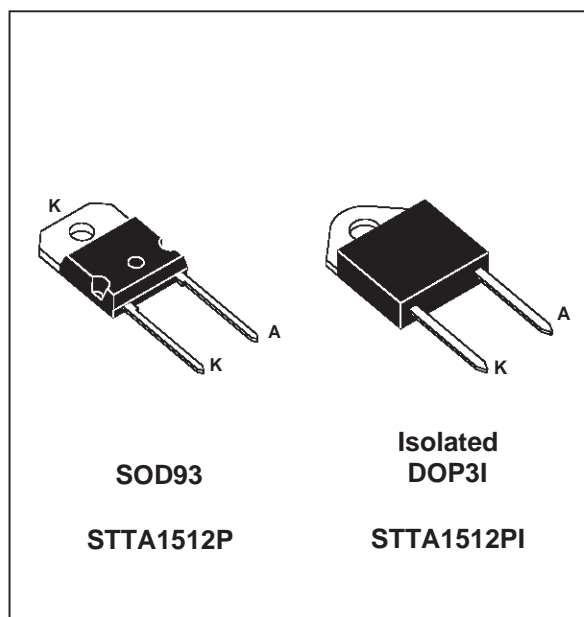
DESCRIPTION

TURBOSWITCH 1200V drastically cuts losses in all high voltage operations which require extremely fast, soft and noise-free power diodes. Due to their optimized switching performances they also highly decrease power losses in any associated switching IGBT or MOSFET in all freewheel mode operations.

They are particularly suitable in motor control circuitries, or in the primary of SMPS as snubber, clamping or demagnetizing diodes. They are also suitable for secondary of SMPS as high voltage rectifier diodes.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		1200	V
$I_{F(RMS)}$	RMS forward current		50	A
I_{FRM}	Repetitive peak forward current	tp = 5 µs F = 5kHz square	220	A
I_{FSM}	Surge non repetitive forward current	tp = 10ms sinusoidal	150	A
T_{stg}	Storage temperature range		- 65 to + 150	°C
T_j	Maximum operating junction temperature		150	°C

THERMAL AND POWER DATA

Symbol	Parameter	Conditions		Value	Unit
$R_{th(j-c)}$	Junction to case thermal resistance	SOD93 DOP3I		1.6 2.1	$^\circ$C/W
P_1	Conduction power dissipation $I_{F(AV)} = 15A$ $\delta = 0.5$	SOD93 DOP3I	Tc= 95°C Tc= 78°C	34	W
P_{max}	Total power dissipation Pmax = P1 + P3 (P3 = 10% P1)	SOD93 DOP3I	Tc= 89°C Tc= 70°C	38	W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions		Min	Typ	Max	Unit
V_F *	Forward voltage drop	I_F =15A	Tj = 25°C Tj = 125°C		 1.3	2.1 1.9	V V
I_R **	Reverse leakage current	V_R =0.8 x V_{RRM}	Tj = 25°C Tj = 125°C		 1.3	100 6.0	μA mA
Vto	Threshold voltage	Ip < 3.$I_{F(AV)}$	Tj = 125°C			1.48	V
Rd	Dynamic resistance		Tj = 125°C			25	mΩ

Test pulses :   * tp = 380 μs, δ < 2%
                  ** tp = 5 ms , δ < 2%

To evaluate the maximum conduction losses use the following equation :
$P = V_{to} \times I_{F(AV)} + Rd \times I_F^2{}_{(RMS)}$

DYNAMIC ELECTRICAL CHARACTERISTICS

TURN-OFF SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{rr}	Reverse recovery time	Tj = 25°C I_F = 0.5 A I_R = 1A Irr = 0.25A I_F = 1 A dI_F/dt =-50A/μs V_R =30V		55 	 105	ns
I_{RM}	Maximum reverse recovery current	Tj = 125°C VR = 600V I_F =15A dI_F/dt = -120 A/μs dI_F/dt = -500 A/μs		 33	 20 	A
S $_{factor}$	Softness factor	Tj = 125°C V_R = 600V I_F =15A dI_F/dt = -500 A/μs		1.2		/

TURN-ON SWITCHING

Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
t_{fr}	Forward recovery time	Tj = 25°C I_F =15 A, dI_F/dt = 120 A/μs measured at 1.1 $\times$ $V_F$max			900	ns
V_{Fp}	Peak forward voltage	Tj = 25°C I_F =15A, dI_F/dt = 120 A/μs I_F =40A, dI_F/dt = 500 A/μs		 40	30 	V

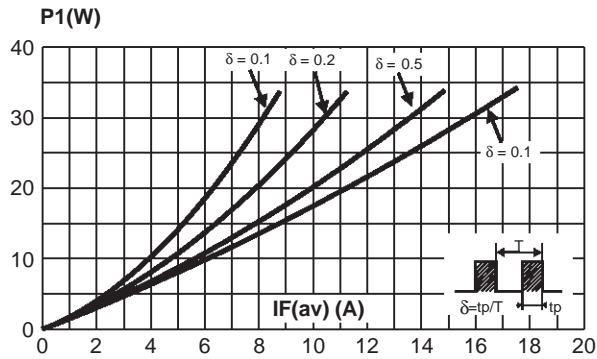**Fig. 1:** Conduction losses versus average current.

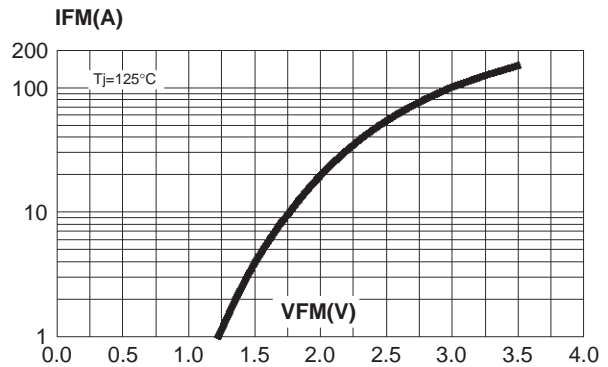**Fig. 2:** Forward voltage drop versus forward current (maximum values).

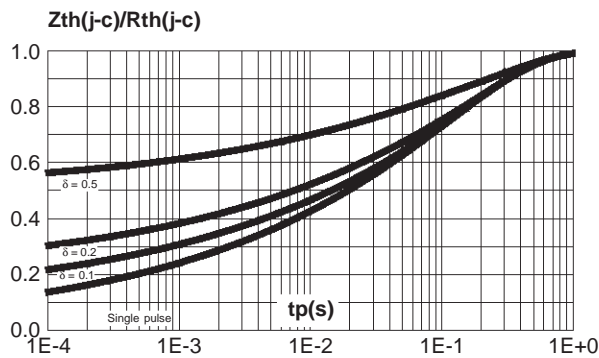**Fig. 3:** Relative variation of thermal impedance junction to case versus pulse duration.

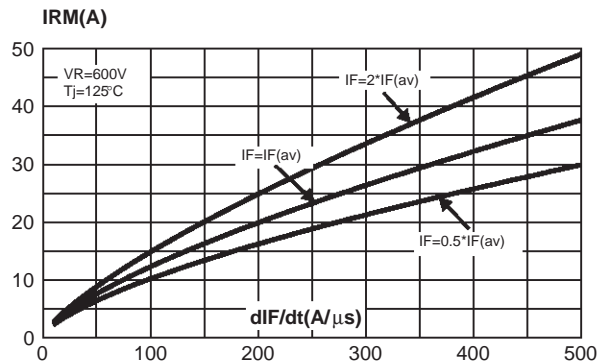**Fig. 4:** Peak reverse recovery current versus dI_F/dt (90% confidence).

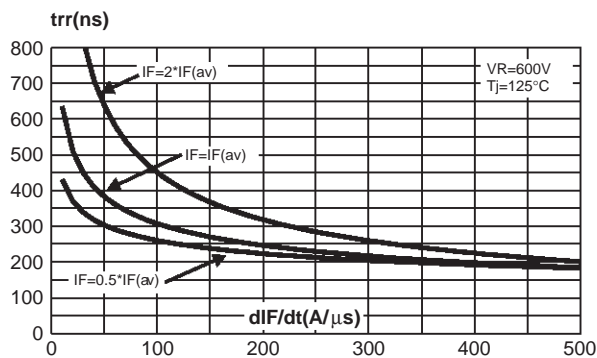**Fig. 5:** Reverse recovery time versus dI_F/dt (90% confidence).

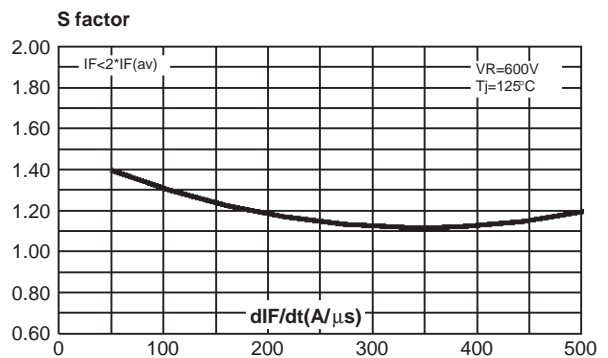**Fig. 6:** Softness factor (tb/ta) versus dI_F/dt (typical values).

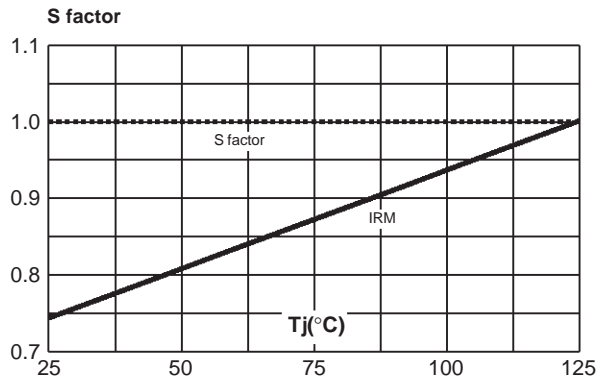**Fig. 7:** Relative variation of dynamic parameters versus junction temperature.

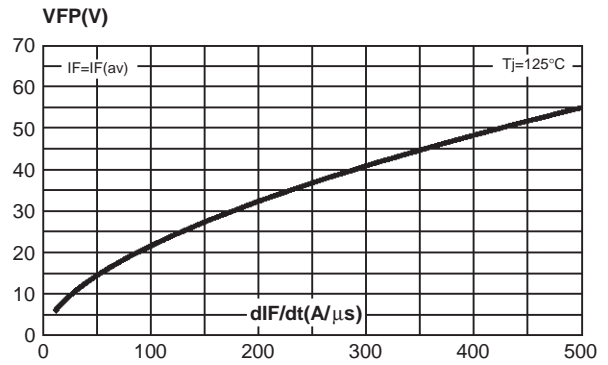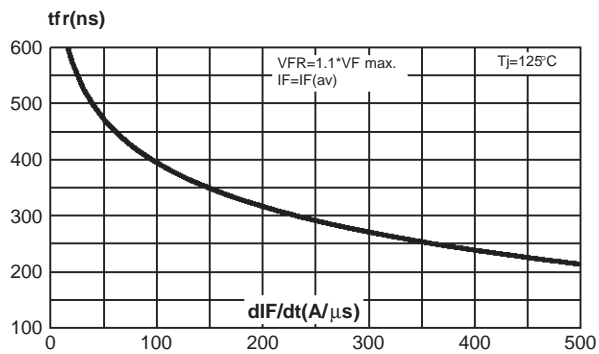**Fig. 8:** Transient peak forward voltage versus dI_F/dt (90% confidence).

Fig. 9: Forward recovery time versus dI_F/dt (90% confidence).

APPLICATION DATA

The 1200V TURBOSWITCH series has been designed to provide the lowest overall power losses in all high frequency or high pulsed current operations. In such applications (Fig A to D),the way of calculating the power losses is given below :
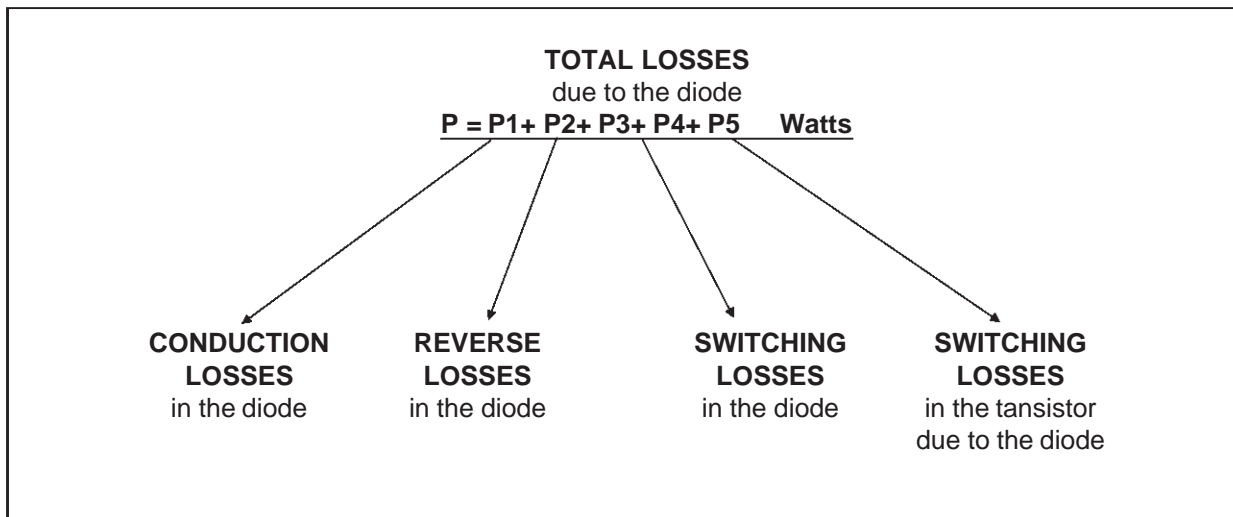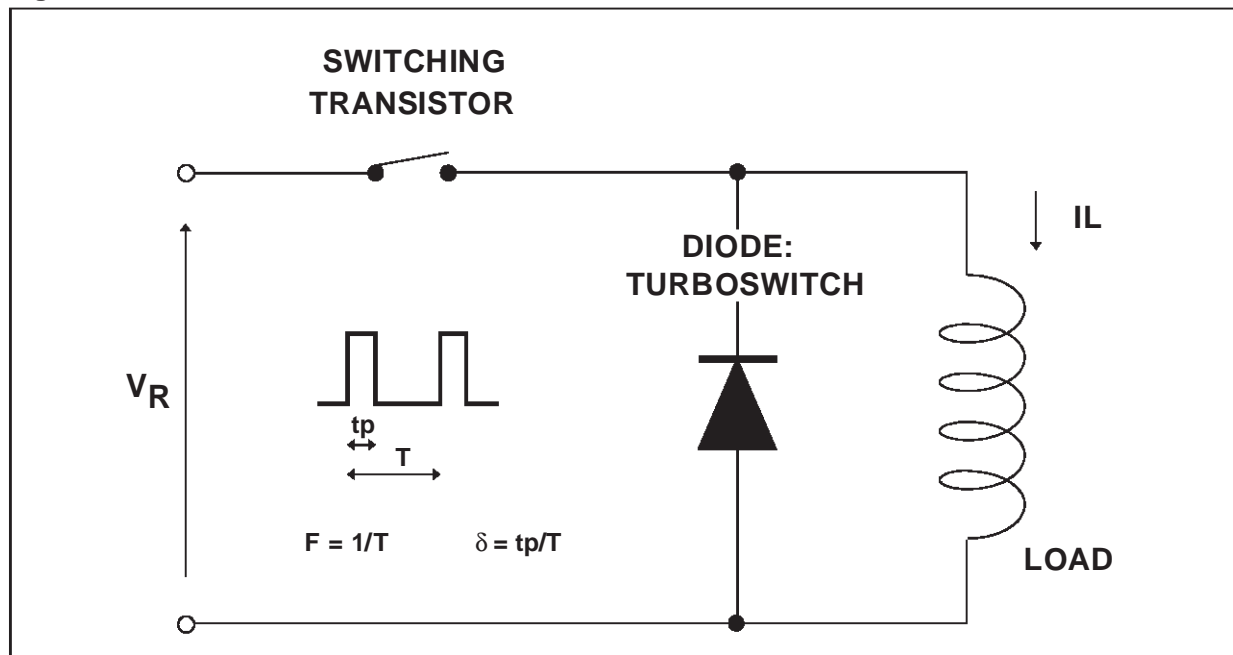
TOTAL LOSSES
due to the diode
P = P1+ P2+ P3+ P4+ P5   Watts

CONDUCTION LOSSES	**REVERSE LOSSES**	**SWITCHING LOSSES**	**SWITCHING LOSSES**
in the diode	in the diode	in the diode	in the tansistor due to the diode

Fig. A : "FREEWHEEL" MODE.

SWITCHING TRANSISTOR

DIODE: TURBOSWITCH

IL

V_R

tp

T

F = 1/T δ = tp/T
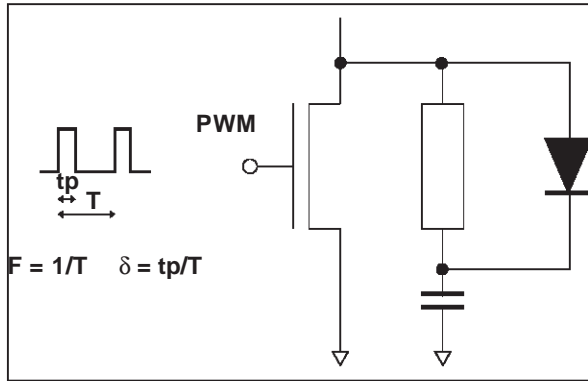
LOAD

Fig. B : SNUBBER DIODE.

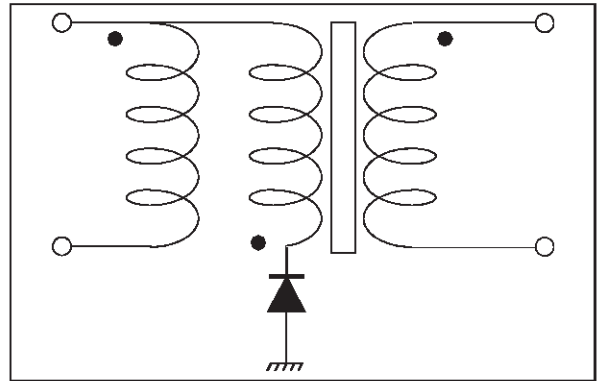**Fig. C :** DEMAGNETIZING DIODE.
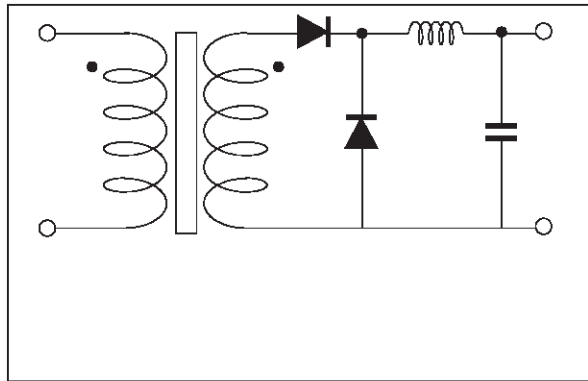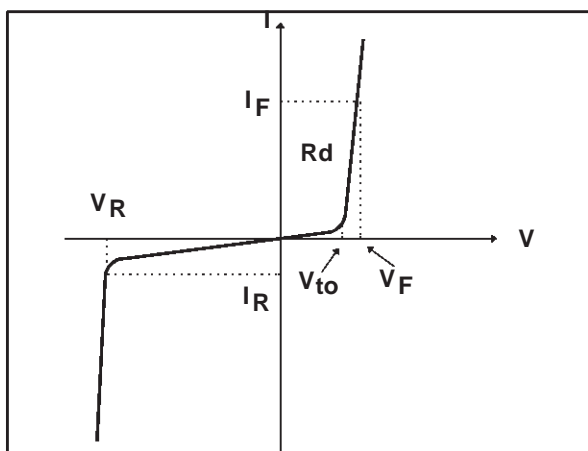

Fig. D : RECTIFIER DIODE.

STATIC & DYNAMIC CHARACTERISTICS . POWER LOSSES .

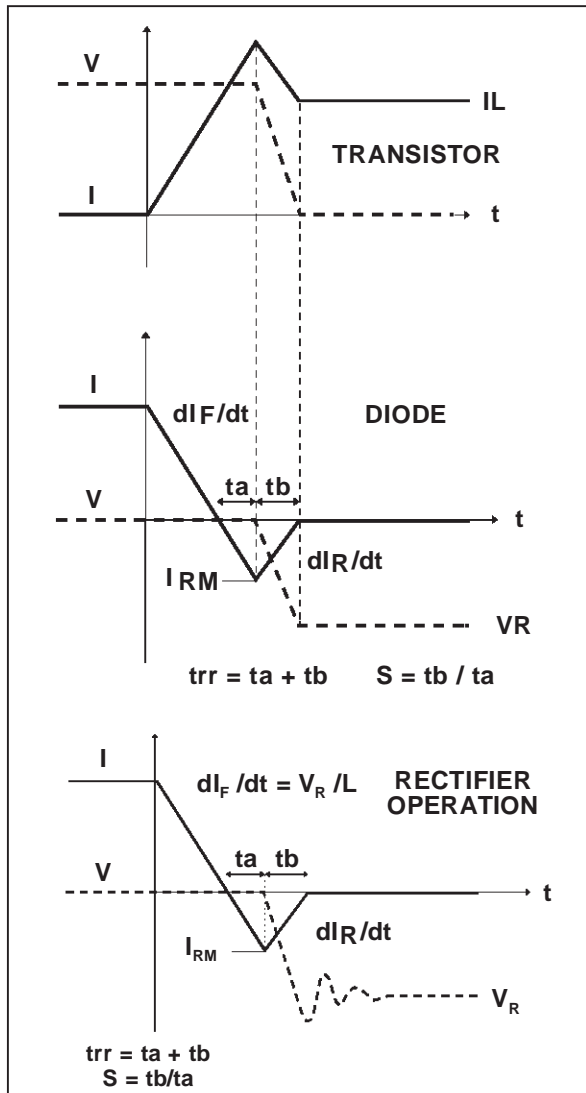**Fig. E:** STATIC CHARACTERISTICS

Conduction losses :

$$P1 = V_{to} . I_{F(AV)} + R_d . I_{F}^{2}{}_{(RMS)}$$

Reverse losses :

$$P2 = V_R . I_R . (1 - \delta)$$

APPLICATION DATA (Cont'd)

Fig. F: TURN-OFF CHARACTERISTICS

Turn-on losses :
(in the transistor, due to the diode)

$$P5 = \frac{V_R \times I_{RM^2} \times (3 + 2 \times S) \times F}{6 \; x \; dI_F / dt}$$
$$+ \frac{V_R \times I_{RM} \times I_L \times (S + 2) \times F}{2 \; x \; dI_F / dt}$$
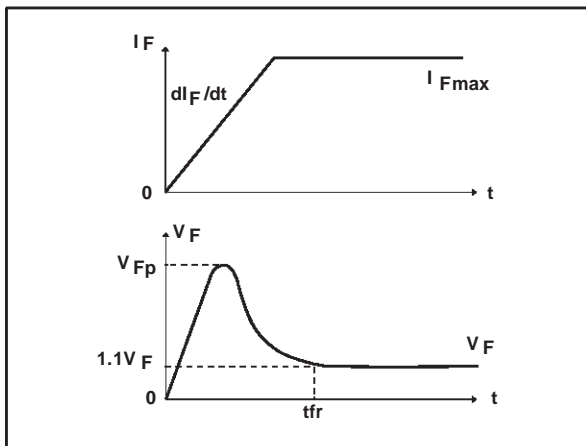
Turn-off losses (in the diode) :

$$P3 = \frac{V_R \times I_{RM^2} \times S \times F}{6 \; x \; dI_F / dt}$$

Turn-off losses :
(with non negligible serial inductance)

$$P3' = \frac{V_R \times I_{RM^2} \times S \times F}{6 \; x \; dI_F / dt} +$$
$$\frac{L \times I_{RM}^2 \times F}{2}$$

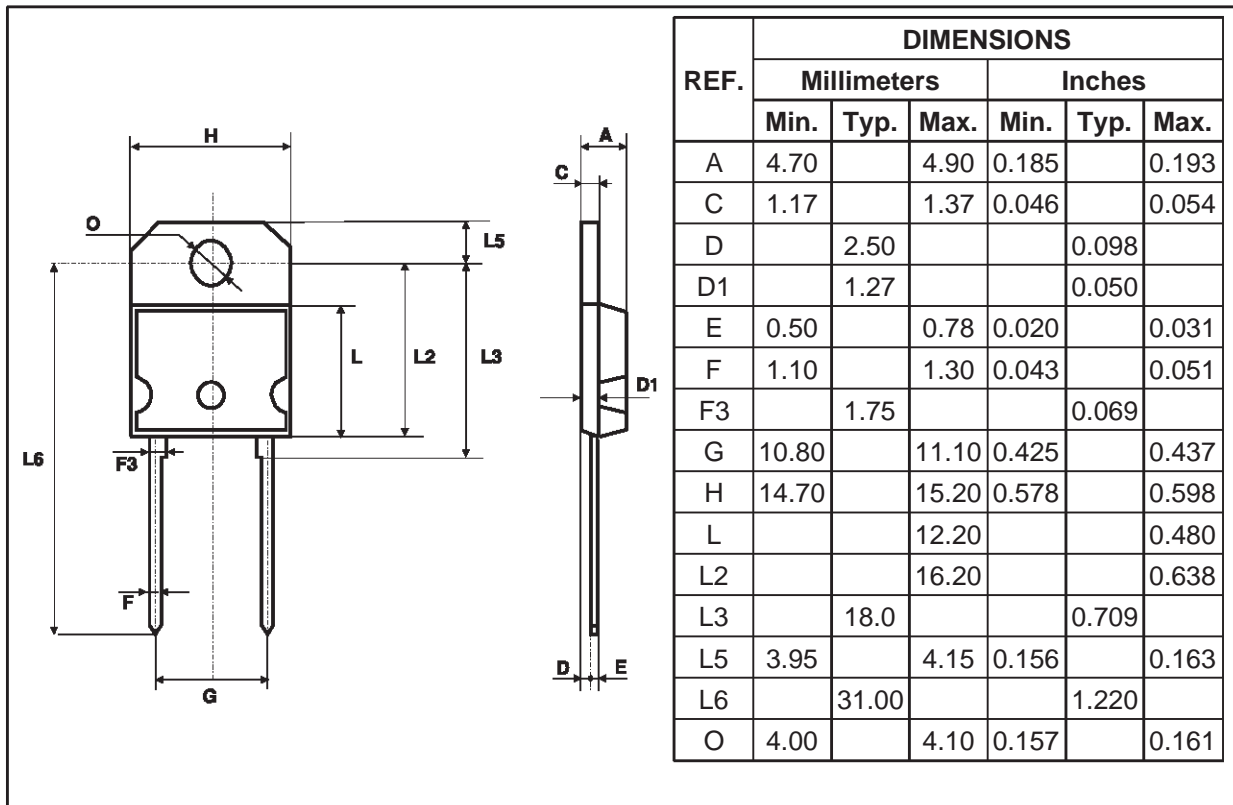P3,P3' and P5 are suitable for power MOSFET and IGBT

Fig. G: TURN-ON CHARACTERISTICS

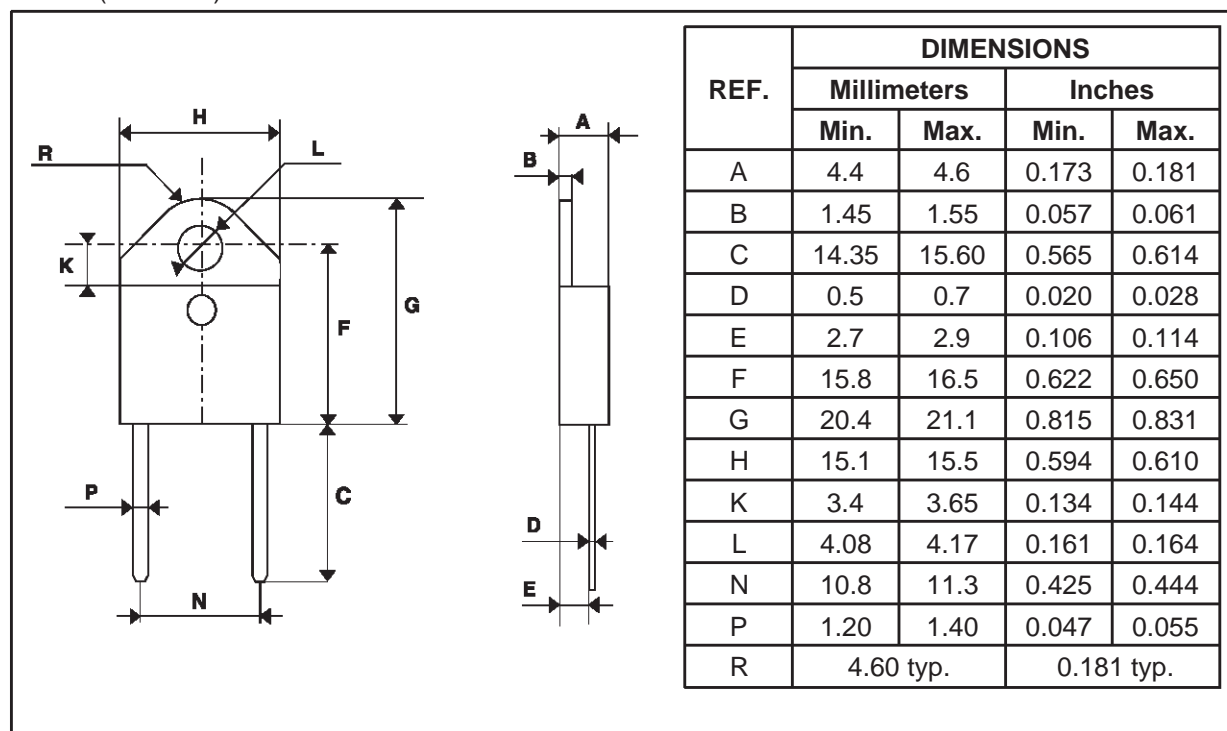**Turn-on** losses :
P4 = 0.4 (V_{FP} - V_F) . I_{Fmax} . t_{fr} . F

PACKAGE MECHANICAL DATA
SOD93

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.70		4.90	0.185		0.193
C	1.17		1.37	0.046		0.054
D		2.50			0.098	
D1		1.27			0.050	
E	0.50		0.78	0.020		0.031
F	1.10		1.30	0.043		0.051
F3		1.75			0.069	
G	10.80		11.10	0.425		0.437
H	14.70		15.20	0.578		0.598
L		12.20				0.480
L2		16.20				0.638
L3		18.0			0.709	
L5	3.95		4.15	0.156		0.163
L6		31.00			1.220	
O	4.00		4.10	0.157		0.161

PACKAGE MECHANICAL DATA
DOP3I (insulated)

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	1.45	1.55	0.057	0.061
C	14.35	15.60	0.565	0.614
D	0.5	0.7	0.020	0.028
E	2.7	2.9	0.106	0.114
F	15.8	16.5	0.622	0.650
G	20.4	21.1	0.815	0.831
H	15.1	15.5	0.594	0.610
K	3.4	3.65	0.134	0.144
L	4.08	4.17	0.161	0.164
N	10.8	11.3	0.425	0.444
P	1.20	1.40	0.047	0.055
R	4.60 typ.		0.181 typ.	

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STTA1512P	STTA1512P	SOD93	3.79g	30	Tube
STTA1512PI	STTA1512PI	DOP3I	4.52g	120	Bulk

- Cooling method: by conduction (C)
- Recommended torque value: 0.8 N.m.
- Maximum torque value: 1.0 N.m.
- Epoxy meets UL94,V0